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# LCP02-150B1

# Protection IC for ringing SLICs

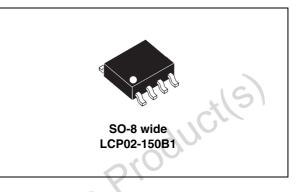
### Datasheet - production data

# Features

- Protection IC recommended for ringing SLICs
- Wide firing voltage range: -120 V to +120 V
- Low gate triggering current: I<sub>G</sub> = 5 mA max
- Peak pulse current: I<sub>PP</sub> = 30 A (10/1000 μs)
- Holding current:  $I_H = 150$  mA min.
- UL497B approved (file E136224)

# **Applications**

- Dual battery supply voltage SLICs
  - negative battery supply configuration
    negative and positive battery supply configuration
- Central office (CO)
- Private branch exchange (PBX)
- Digital loop carrier (DLC)
- Asymmetrical digital subscriber line (ADSL G.Lite)
- Fiber in the loop (FITL)
- Wireless local loop (WLL)
- Hybrid fiber coax (HFC)
- ISDN terminal adapter
- Cable modem



# Description

The LCP02-150B1 has been developed to protect SLICs operating on both negative and positive battery supplies, as well as high voltage SLICs. It provides crowbar mode protection for both TIP and RING lines. The surge suppression is managed for each wire by two thyristor structures, one dedicated to positive surges the second one for negative surges. Both positive and negative threshold levels are programmable by two gates (Gn and Gp). The use of transistors decreases the battery currents during surge suppression.

LCP02-150B1 can be used to help equipment to meet various standards such as UL1950, IEC 60950 / CSAC22.2, UL1459 and TIA-968-A (formerly FCC part68). A Trisil<sup>™</sup> meets UL94 V0 (Trisils are UL497B approved - file: E136224).

TM: Trisil is a trademark of STMicroelectronics

Doc ID 7275 Rev 8

This is information on a product in full production.

### **Characteristics** 1

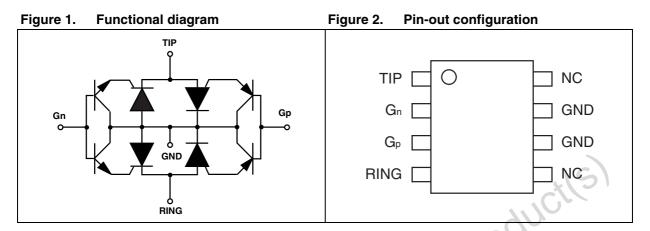


Table 1.      Compliant with the followin	g standards			O	
Standard	Peak surge voltage (V)	Voltage waveform	Required peak current (A)	Current waveform	Minimum serial resistor to meet standard (Ω)
GR1089 core first level	2500 1000	2/10 μs 10/1000 μs	500 100	2/10 μs 10/1000 μs	20.0 24
GR1089 core second level	5000	2/10 µs	500	2/10 µs	40
GR1089 core intra-building	1500	2/10 µs	100	2/10 µs	0
ITU-T-K20/K21	6000 4000 1500	10/700 µs	150 100 37.5	5/310 µs	94 49 0
ITU-T-K20 (IEC61000-4-2)	8000 15000	1/60 ns	ESD contac ESD air c		0 0
IEC61000-4-5	4000 4000	10/700 μs 1.2/50 μs	100 100	5/310 μs 8/20 μs	49 0
TIA-968-A (formerly FCC part 68) type A	1500 800	10/160 μs 10/560 μs	200 100	10/160 μs 10/560 μs	20 15
TIA-968-A (formerly FCC part 68) type B	1000	9/720 µs	25	5/320 µs	0

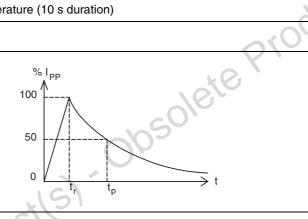




Symbol	Parameter		Value	Unit
I <sub>PP</sub>	Peak pulse current	10/1000 μs 5/310 μs 2/10μs	30 45 100	А
I <sub>TSM</sub>	Non repetitive surge peak on-state current (F = 50 Hz) $I_{TSM}$ value specified for each line $I_{TSM}$ value can be applied on both lines at the same time (GND capability is twice the line $I_{TSM}$ )	$t_p = 0.2 \text{ s}$ $t_p = 1 \text{ s}$ $t_p = 15 \text{ min.}$	9 6 1.9	A
V <sub>Gn</sub> V <sub>Gp</sub>	Negative battery voltage range Positive battery voltage range		-120 to 0 0 to +120	v
Тj	Operating junction temperature range		-40 to +125	°C
T <sub>stg</sub>	Storage temperature range		-55 to +150	°C
ΤL	Lead solder temperature (10 s duration)		260	°C

### Table 2. Absolute maximum ratings ( $T_{amb} = 25 \text{ °C}$ )

### Figure 3. Pulse waveform



### Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R <sub>th(j-a)</sub>	Junction to ambient	150	°C/W

## Table 4. Parameters related to the negative suppressor

Symbol	Parameter	Test conditions	Min.	Max.	Unit
O <sub>Gn</sub>	Negative gate trigger current	V <sub>Gn/GND</sub> = -60 V Measured at 50 Hz		5	mA
I <sub>H-</sub>	Holding current (see Figure 4)	Go-No Go test, V <sub>Gn</sub> = -60 V	150		mA
V <sub>DGL-</sub>	Dynamic switching voltage Gn / Line <sup>(1)</sup>	$\begin{split} V_{Gn/GND} &= -60 \ V \\ 10/700 \ \mu s & 2 \ kV & R_P = 25 \ \Omega & I_{PP} = 30 \ A \\ 1.2/50 \ \mu s & 2 \ kV & R_P = 25 \ \Omega & I_{PP} = 30 \ A \end{split}$		8 15	v

1. The  $V_{DGL}$  value is the difference between the peak line voltage during the surge and the programmed gate voltage.



Symbol	Parameter	Test conditions	Min.	Max.	Unit
I <sub>Gp</sub>	Positive gate trigger current	$V_{Gp/GND}$ = 60 V, measured at 50 Hz		5	mA
		$V_{Gp/GND} = 60 V$			
$V_{DGL+}$	Dynamic switching voltage Gp / Line <sup>(1)</sup>	10/700 μs 2 kV $R_P = 25 \Omega$ $I_{PP} = 30 A$		8	V
		1.2/50 $\mu$ s 2 kV R <sub>P</sub> = 25 $\Omega$ I <sub>PP</sub> = 30 A		35	

Table 5. Parameters related to the positive suppressor

1. The V<sub>DGL</sub> value is the difference between the peak line voltage during the surge and the programmed gate voltage.

#### Parameters related to line/GND Table 6.

Symbol	Parameter	Test conditions	Min.	Max.	Unit
I <sub>R</sub>	Reverse leakage current	$ \begin{array}{ll} T_{j} = 25 \ ^{\circ}C & V_{LINE} = +120 \ V & V_{Gp/LINE} = +1 \ V \\ T_{j} = 25 \ ^{\circ}C & V_{LINE} = -120 \ V & V_{Gn/LINE} = -1 \ V \end{array} $		55	μA
C <sub>off</sub>	Capacitance LINE/GND	$V_{R}$ = -3 V, F =1 MHz, $V_{Gp}$ = 60 V, $V_{Gn}$ = -60 V	20	60	pF

#### Table 7. **Recommended gate capacitance**

Symbol	Component	Min.	Тур.	Max.
C <sub>G</sub>	Gate decoupling capacitance	100	220	
	Obs			
	*(5)			
	duct(S)			
	e Product(S)			
	ste Product(S)			



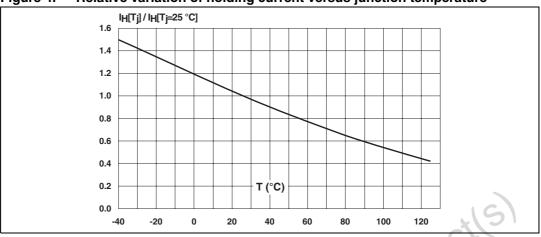
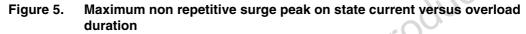
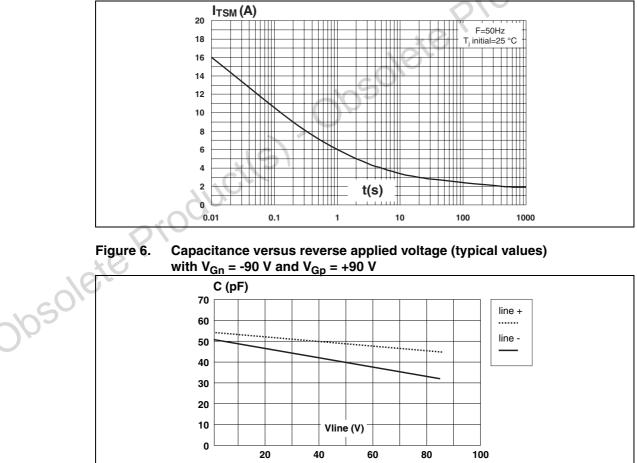
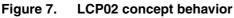


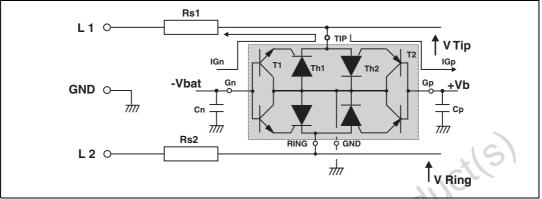
Figure 4. Relative variation of holding current versus junction temperature





# 2 Technical information





*Figure 7* shows the classical protection circuit using the LCP02 crowbar concept. This topology has been developed to protect the new two-battery voltage SLICs. It allows both positive and negative firing thresholds to be programmed. The LCP02 has two gates (Gn and Gp). Gn is biased to negative battery voltage -Vbat, while Gp is biased to the positive battery voltage +Vb.

When a negative surge occurs on one wire (L1 for example), a current IGn flows through the base of the transistor T1 and then injects a current in the gate of the thyristor Th1 which fires. All the surge current flows through the ground. After the surge, when the current flowing through Th1 becomes less negative than the negative holding current  $I_{H-}$ , Th1 switches off. This holding current  $I_{H-}$  is temperature dependant as per *Figure 4* 

When a positive surge occurs on one wire (L1 for example), a current IGp flows through the base of the transistor T2 and then injects a current in the gate of the thyristor Th2 which fires. All the surge current flows through the ground. After the surge, when the current flowing through Th2 becomes less positive than the positive holding current I<sub>H+</sub>, Th2 switches off. This holding current I<sub>H+</sub>, typically 20 mA at 25 °C, is temperature dependant and the same *Figure 4* also applies.

The capacitors Cn and Cp are used to speed up the crowbar structure firing during the fast rise or fall edges. This allows minimization of the dynamic breakover voltage at the SLIC TIP and RING inputs during fast surges. Please note that these capacitors are generally available around the SLIC. To be efficient they have to be as close as possible to the LCP02 gate pins (Gn and Gp) and to the reference ground track (or plan). The optimized value for Cn and Cp is 220nF.



The series resistors Rs1 and Rs2 designed in *Figure 7* represent the fuse resistors or the PTCs which are needed to withstand the power contact or the power induction tests imposed by the country standards. Taking this factor into account, the actual lightning surge current flowing through the LCP02-150B1 is equal to:

I surge = Vsurge / (Rg + Rs)

With

V surge = peak surge voltage imposed by the standard.

Rg = series resistor of the surge generator

Rs = series resistor of the line card (e.g. PTC)

For a line card with 50  $\Omega$  of series resistors which has to be qualified under GR-1089 1000 V 10/1000 µs surge, the present current through the LCP02-150B1 is equal to:

I surge = 1000 / (10 + 50) = 17 A

The LCP02-150B1 topology is particularly optimized for the new telecom applications such as fiber in the loop, WLL systems, decentralized central office for example.



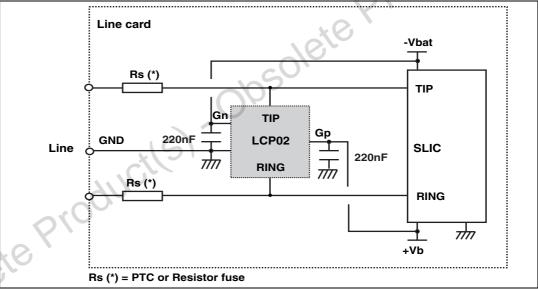


Figure 8 shows the classical protection topology for SLIC using both positive and negative battery voltages. With such a protection the SLIC is protected against surge over +Vb and lower than -Vbat. In this case, +Vb can be programmed up to +120 V while -Vbat can be programmed down to -120 V.

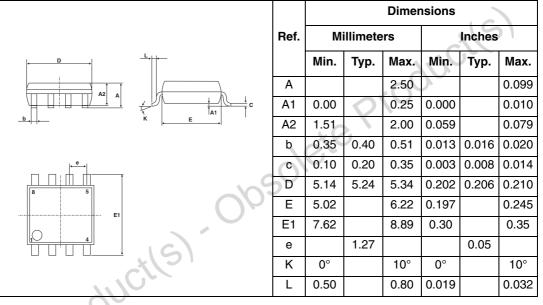


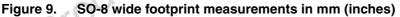
# 3 Package information

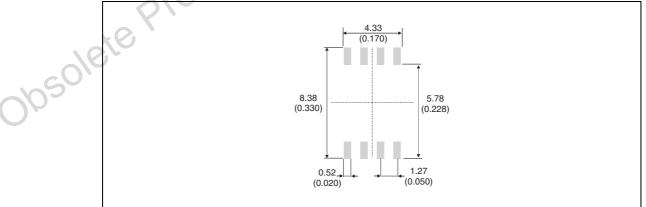
- Epoxy meets UL94, V0
- Lead-free package

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Table 8. SO-8 wide dimensions









### **Ordering information** 4

#### Table 9. **Ordering information**

Order code	Marking	Package	Weight	Base qty	Delivery mode
LCP02-150B1RL	LCP02	SO-8-Wide	0.13g	1500	Tape and reel

### 5 **Revision history**

#### Table 10. **Document revision history**

Date	Revision	Changes
Sep-2000	4A	Previous release.
17-Oct-2008	5	Reformatted to current standards. Vline updated to 120 V in Table 6.
28-Jun-2010	6	Removed 1 kV values for $V_{DGL-}$ in <i>Table 4</i> , and $V_{DGL+}$ in <i>Table 5</i> . Added symbol and trademark statement for Trisil on the cover page. Updated package dimension graphics.
 23-Feb-2012	7	Updated nomenclature for GN to Gn and GP to Gp.
19-Jun-2012	8	Updated dimension D in SO-8 wide



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